

SEMICONDUCTOR

BCV71

NPN General Purpose Amplifier

- This device is designed for general purpose applications at collector currents to 300mA.
- Sourced from process 10.



1. Base 2. Emitter 3. Collector

Absolute Maximum Ratings * T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units	
CEO	Collector-Emitter Voltage	60	V	
сво	Collector-Base Voltage	80	V	
/ _{EBO}	Emitter-Base Voltage	5.0	V	
С	Collector current (DC)	500	mA	
J, T _{sta}	Operating and Storage Junction Temperature Range	-55 ~ +150	°C	

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Electrical Characteristics Ta=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units	
Off Charact	Off Characteristics						
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 10 \mu {\rm A}, \ I_{\rm E} = 0$	80			V	
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 2{\rm mA}, I_{\rm B} = 0$	60			V	
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{\rm E} = 10\mu A, I_{\rm C} = 0$	5.0			V	
I _{CBO}	Collector Cutoff Current	$V_{CB} = 20V, I_E = 0$			100	nA	
		$V_{CB} = 20V, I_E = 0, T_a = 100^{\circ}C$			10	μA	
On Charact	eristics						
h _{FE}	DC Current Gain	$I_{C} = 2.0 \text{mA}, V_{CE} = 5.0 \text{V}$	110		220		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0.5 {\rm mA}$			0.25	V	
V _{BE(on)}	Base-Emitter On Voltage	I _C = 2.0mA, V _{CE} = 5.0V	0.55		0.7	V	

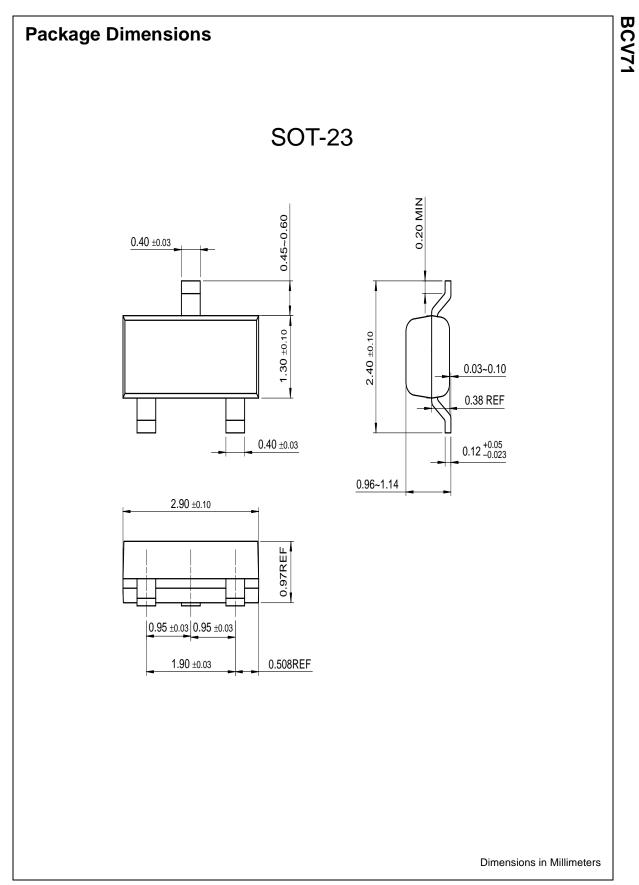
Thermal Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Max.	Units
PD	Total Device Dissipation	350	mW
2	Derate above 25°C	2.8	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

Device mounted on FR-4PCB 40mm × 40mm × 1.5mm

Rev. A, April 2004

©2004 Fairchild Semiconductor Corporation



©2004 Fairchild Semiconductor Corporation

TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACEx™	FACT Quiet Series™	ImpliedDisconnect™	PACMAN™	SPM™
ActiveArray™	FAST®	ISOPLANAR™	POP™	Stealth™
Bottomless™	FASTr™	LittleFET™	Power247™	SuperFET™
CoolFET™	FPS™	MICROCOUPLER™	PowerSaver™	SuperSOT™-3
CROSSVOLT™	FRFET™	MicroFET™	PowerTrench [®]	SuperSOT™-6
DOME™	GlobalOptoisolator™	MicroPak™	QFET [®]	SuperSOT™-8
EcoSPARK™	GTO™່	MICROWIRE™	QS™	SyncFET™
E ² CMOS™	HiSeC™	MSX™	QT Optoelectronics [™]	TinyLogic®
EnSigna™	l²C™	MSXPro™	Quiet Series [™]	TINYOPTO™
FACT™	<i>i-Lo</i> ™	OCX™	RapidConfigure™	TruTranslation™
Across the boar	d. Around the world.™	OCXPro™	RapidConnect™	UHC™
The Power Fran		OPTOLOGIC [®]	SILENT SWITCHER [®]	UltraFET [®]
Programmable A		OPTOPLANAR™	SMART START™	VCX™

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user. 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.
	•	Rev. 110